

Switch Mode Power Rectifiers MBR440MFS, NRVB440MFS

These state-of-the-art devices have the following features:

Features

- Low Power Loss / High Efficiency
- New Package Provides Capability of Inspection and Probe After Board Mounting
- Guardring for Stress Protection
- Low Forward Voltage Drop
- 175°C Operating Junction Temperature
- NRVB Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- WF Suffix for Products with Wettable Flanks
- These are Pb-Free and Halide-Free Devices

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94–0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements

Applications

- Ideally Suited for use as an Output Rectifier in High Frequency (up to 2 MHz) Automotive and Non-Automotive Applications
- Output Rectification in Compact Portable Consumer Applications
- Freewheeling Diode used with Inductive Loads

SCHOTTKY BARRIER RECTIFIERS 4 AMPERES 40 VOLTS

1,2,3 0 5,6

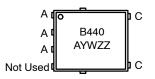




SO-8 FLAT LEAD CASE 488AA STYLE 2

(FULL-CUT SO8FL WF) CASE 507BA DFNW5

MARKING DIAGRAM



B440 = Specific Device Code A = Assembly Location

Y = Year
W = Work Week
ZZ = Lot Traceability

ORDERING INFORMATION

Device	Package	Shipping†
MBR440MFST1G	SO-8 FL (Pb-Free)	1500 / Tape & Reel
MBR440MFST3G	SO-8 FL (Pb-Free)	5000 / Tape & Reel
NRVB440MFST1G	SO-8 FL (Pb-Free)	1500 / Tape & Reel
NRVB440MFST3G	SO-8 FL (Pb-Free)	5000 / Tape & Reel
NRVB440MFSWFT1G	SO-8 FL (Pb-Free)	1500 / Tape & Reel
NRVB440MFSWFT3G	SO-8 FL (Pb-Free)	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MBR440MFS, NRVB440MFS

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	V
Average Rectified Forward Current (Rated V _R , T _C = 165°C)	I _{F(AV)}	4.0	A
Peak Repetitive Forward Current, (Rated V _R , Square Wave, 20 kHz, T _C = 165°C)	I _{FRM}	8.0	А
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	40	А
Storage Temperature Range	T _{stg}	-65 to +175	°C
Operating Junction Temperature	TJ	-55 to +175	°C
Unclamped Inductive Switching Energy (10 mH Inductor, Non-repetitive)	E _{AS}	10	mJ
ESD Rating (Human Body Model)		3B	
ESD Rating (Machine Model)		M4	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

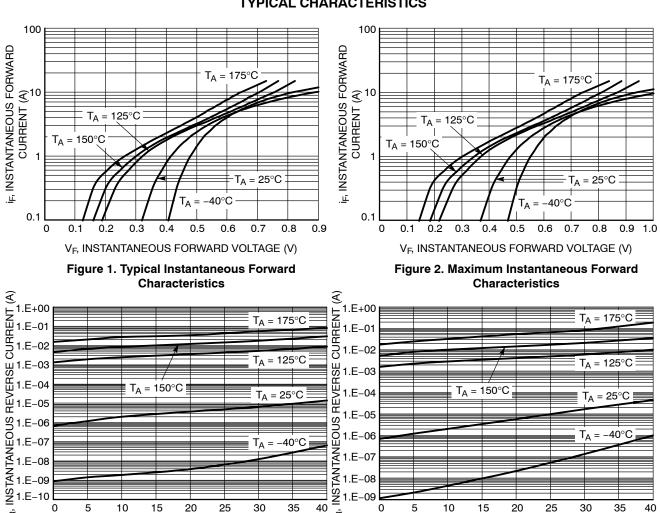
Characteristic	Symbol	Тур	Max	Unit	
Thermal Resistance, Junction-to-Case, Steady State (Assumes 600 mm ² 1 oz. copper bond pad, on a FR4 board)	$R_{ heta JC}$	Г	2.4	°C/W	
ELECTRICAL CHARACTERISTICS					

Instantaneous Forward Voltage (Note 1) ($i_F = 4$ Amps, $T_J = 125$ °C) ($i_F = 4$ Amps, $T_J = 25$ °C)	v _F	0.58 0.59	0.63 0.65	V
Instantaneous Reverse Current (Note 1)	i _R			mA
(Rated dc Voltage, T _J = 125°C)		10	15	
(Rated dc Voltage, T _J = 25°C)		0.070	8.0	

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

MBR440MFS, NRVB440MFS

TYPICAL CHARACTERISTICS



 $T_A = 25^{\circ}C$

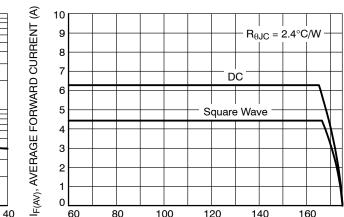
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V_R, INSTANTANEOUS REVERSE VOLTAGE (V) Figure 3. Typical Reverse Characteristics

T_A = 150°C

15



T_A = 150°C

15

V_R, INSTANTANEOUS REVERSE VOLTAGE (V)

Figure 4. Maximum Reverse Characteristics

 $T_A = 25^{\circ}C$

1000 $T_J = 25^{\circ}C$ C, JUNCTION CAPACITANCE (pF) 10 20 0 V_R, REVERSE VOLTAGE (V)

Figure 5. Typical Junction Capacitance

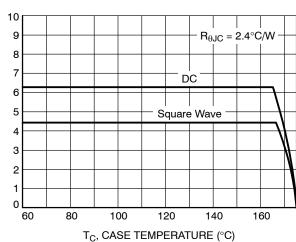


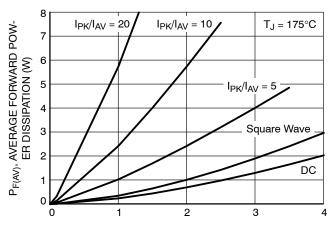
Figure 6. Current Derating TO-220AB

1.E-06 1.E-07 1.E-08 1.E-09 1.E-10

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MBR440MFS, NRVB440MFS

TYPICAL CHARACTERISTICS



I_{F(AV)}, AVERAGE FORWARD CURRENT (A)

Figure 7. Forward Power Dissipation

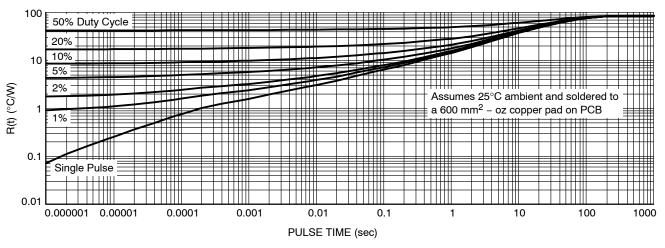


Figure 8. Thermal Characteristics



0.10

0.10

SIDE VIEW

DFN5 5x6, 1.27P (SO-8FL) CASE 488AA ISSUE N

DATE 25 JUN 2018

NOTES:

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION D1 AND E1 DO NOT INCLUDE MOLD FLASH PROTRUSIONS OR GATE BURRS

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.90	1.00	1.10	
A1	0.00		0.05	
b	0.33	0.41	0.51	
С	0.23	0.28	0.33	
D	5.00	5.15	5.30	
D1	4.70	4.90	5.10	
D2	3.80	4.00	4.20	
E	6.00	6.15	6.30	
E1	5.70	5.90	6.10	
E2	3.45	3.65	3.85	
е	1.27 BSC			
G	0.51	0.575	0.71	
K	1.20	1.35	1.50	
L	0.51	0.575	0.71	
L1	0.125 REF			
M	3.00	3.40	3.80	
θ	0 °		12 °	

GENERIC MARKING DIAGRAM*



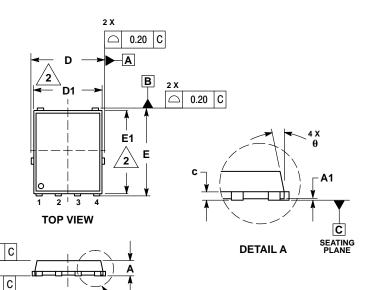
XXXXXX = Specific Device Code

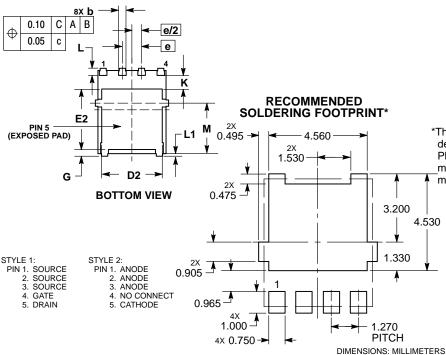
= Assembly Location Α

Υ = Year W = Work Week

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*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.





DETAIL A

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON14036D	Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	DFN5 5x6, 1.27P (SO-8FL)		PAGE 1 OF 1

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IDENTIFIER

// 0.10 C

○ 0.10 C

DFNW5 5x6 (FULL-CUT SO8FL WF)

CASE 507BA **ISSUE A**

В

SEATING PLANE

DATE 03 FEB 2021

MILLIMETERS

NDM.

MAX.

1.10 0.05 0.51

0.33

5.30 5.10

4.20

6.30 6.10

3.85

0.71

1.50

0.71

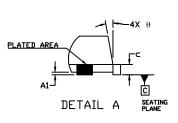
3.80

12*



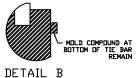
DIM

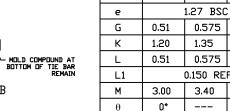
DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
CONTROLLING DIMENSION: MILLIMETERS
DIMENSIONS DI AND EI DO NOT INCLUDE MOLD FLASH,
PROTRUSIONS, OR GATE BURRS.
THIS PACKAGE CONTAINS WETTABLE FLANK DESIGN
FEATURES TO AID IN FILLET FORMATION ON THE LEADS DURING MOUNTING.

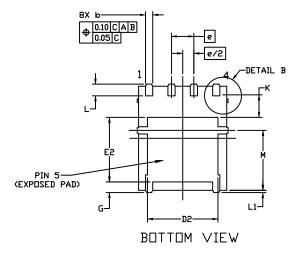


Α	0.90	1.00
A1	0.00	
۵	0.33	0.41
U	0.23	0.28
D	5.00	5.15
D1	4.70	4.90
D2	3.80	4.00
Ε	6.00	6.15
E1	5.70	5.90
F۶	3.45	3.65

MIN.



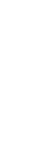




TOP VIEW

SIDE VIEW

DETAIL A



2X 0.4950-4.56 2x 1.53 2X 0.475 PACKAGE DUTLINE 2X 0.905 0.965 4X 1.00-4X 0.75

RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the $\ensuremath{\square} N$ Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



= Assembly Location Α

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may not follow the Generic Marking.

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